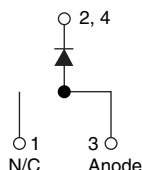




Hyperfast Rectifier, 6 A FRED Pt®



D-PAK (TO-252AA)



FEATURES

- Hyperfast recovery time, extremely low Q_{rr}
- 175 °C maximum operating junction temperature
- For PFC CCM operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition



RoHS
COMPLIANT
HALOGEN
FREE

PRODUCT SUMMARY

Package	D-PAK (TO-252AA)
$I_{F(AV)}$	6 A
V_R	600 V
V_F at I_F	3.1 V
t_{rr} (typ.)	14 ns
T_J max.	175 °C
Diode variation	Single die

DESCRIPTION/APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	V_{RRM}		600	V
Average rectified forward current	$I_{F(AV)}$	$T_C = 136\text{ °C}$	6	A
Non-repetitive peak surge current	I_{FSM}	$T_J = 25\text{ °C}$	50	
Peak repetitive forward current	I_{FM}	$T_C = 136\text{ °C}$, $f = 20\text{ kHz}$, $d = 50\%$	12	
Operating junction and storage temperatures	T_J, T_{Stg}		- 65 to 175	°C

ELECTRICAL SPECIFICATIONS ($T_J = 25\text{ °C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_R	$I_R = 100\text{ }\mu\text{A}$	600	-	-	V
Forward voltage	V_F	$I_F = 6\text{ A}$	-	2.50	3.1	
		$I_F = 6\text{ A}$, $T_J = 150\text{ °C}$	-	1.65	1.9	
Reverse leakage current	I_R	$V_R = V_R$ rated	-	-	20	μA
		$T_J = 150\text{ °C}$, $V_R = V_R$ rated	-	-	250	
Junction capacitance	C_T	$V_R = 600\text{ V}$	-	3.5	-	pF
Series inductance	L_S	Measured lead to lead 5 mm from package body	-	8	-	nH

VS-6EWX06FN-M3

Vishay Semiconductors Hyperfast Rectifier, 6 A FRED Pt®



DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t_{rr}	$I_F = 1\text{ A}$, $di_F/dt = 100\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$	-	14	21	ns
		$I_F = 1\text{ A}$, $di_F/dt = 50\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$	-	16	-	
		$T_J = 25\text{ }^{\circ}\text{C}$	-	19	-	
		$T_J = 125\text{ }^{\circ}\text{C}$	-	27	-	
Peak recovery current	I_{RRM}	$T_J = 25\text{ }^{\circ}\text{C}$	-	3.0	-	A
		$T_J = 125\text{ }^{\circ}\text{C}$	-	4.0	-	
Reverse recovery charge	Q_{rr}	$T_J = 25\text{ }^{\circ}\text{C}$	-	28	-	nC
		$T_J = 125\text{ }^{\circ}\text{C}$	-	57	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T_J, T_{Stg}		- 65	-	175	$^{\circ}\text{C}$
Thermal resistance, junction to case per leg	R_{thJC}		-	-	3	$^{\circ}\text{C}/\text{W}$
Approximate weight			0.3			g
			0.01			oz.
Marking device		Case style D-PAK (TO-252AA)	6EWX06FN			

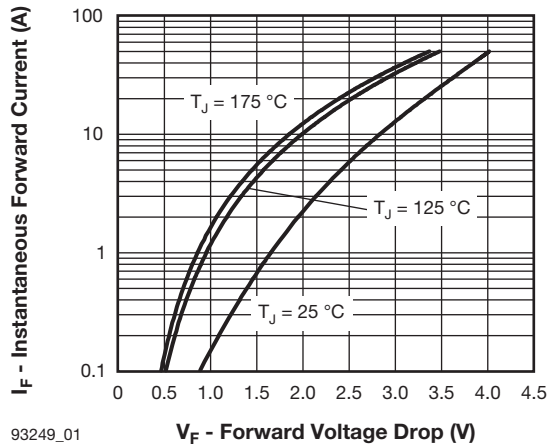


Fig. 1 - Typical Forward Voltage Drop Characteristics

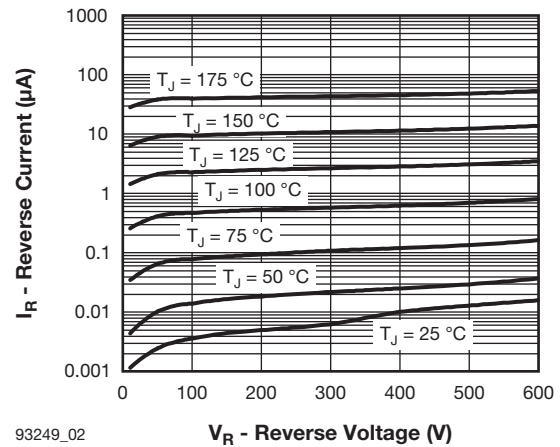


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

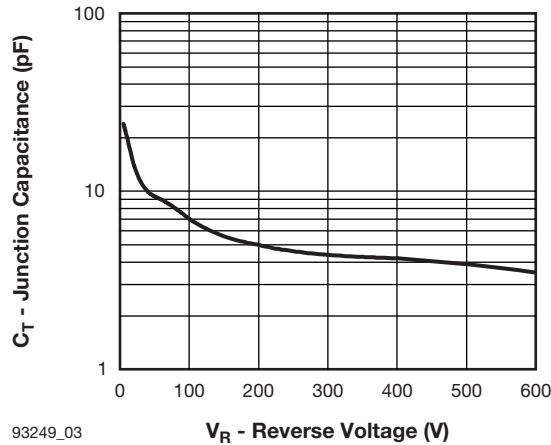
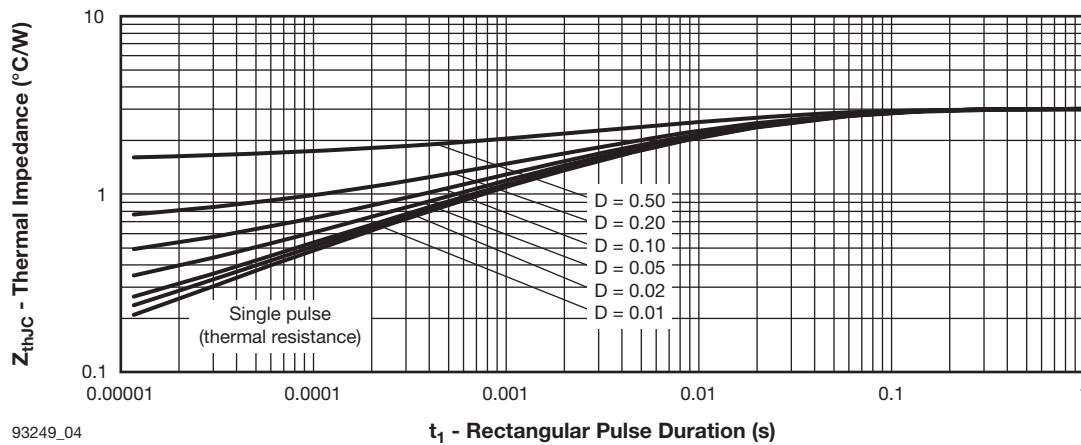
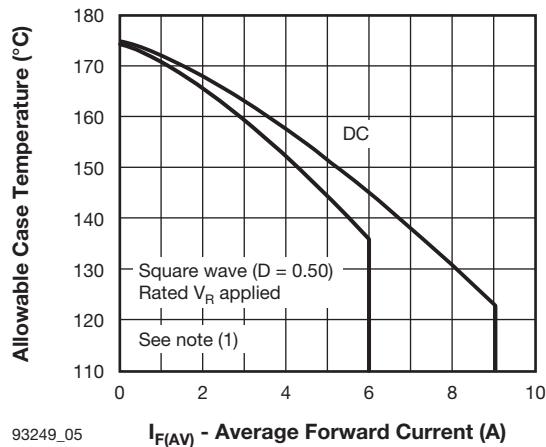


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

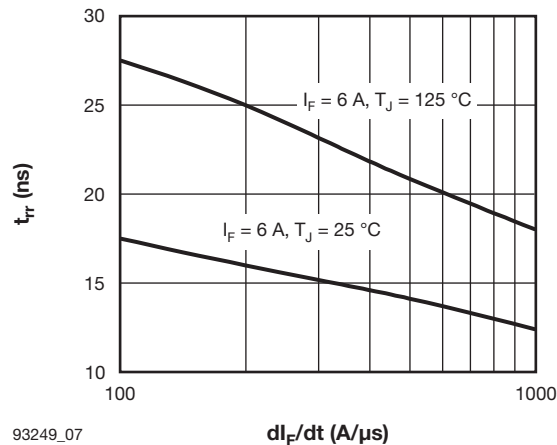
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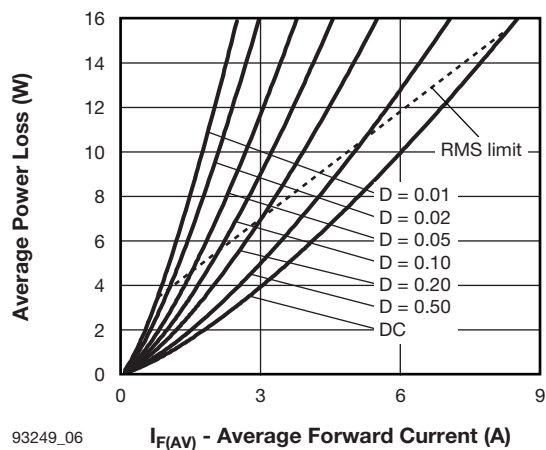


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Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

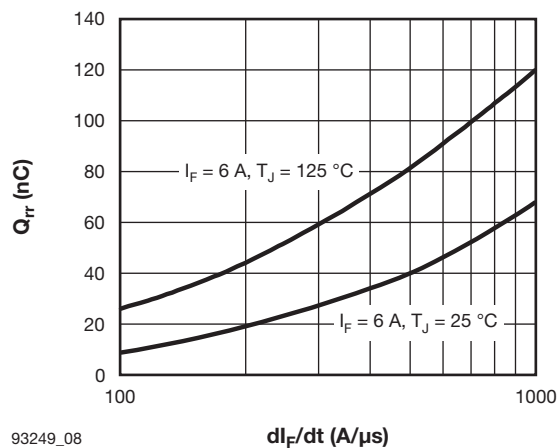


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Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt 

93249_06

Fig. 6 - Forward Power Loss Characteristics



93249_08

Fig. 8 - Typical Stored Charge vs. dI_F/dt **Note**

- (1) Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;
 P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 P_{dREV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = Rated V_R

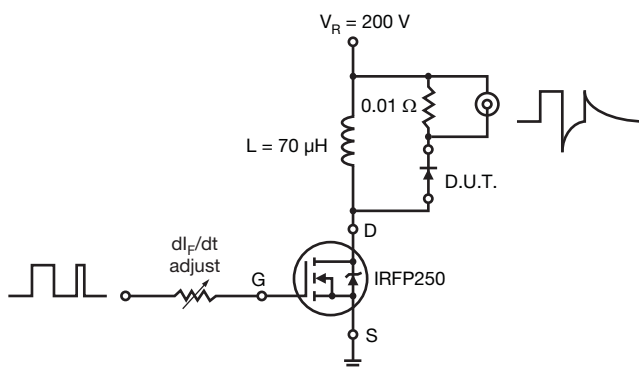


Fig. 9 - Reverse Recovery Parameter Test Circuit

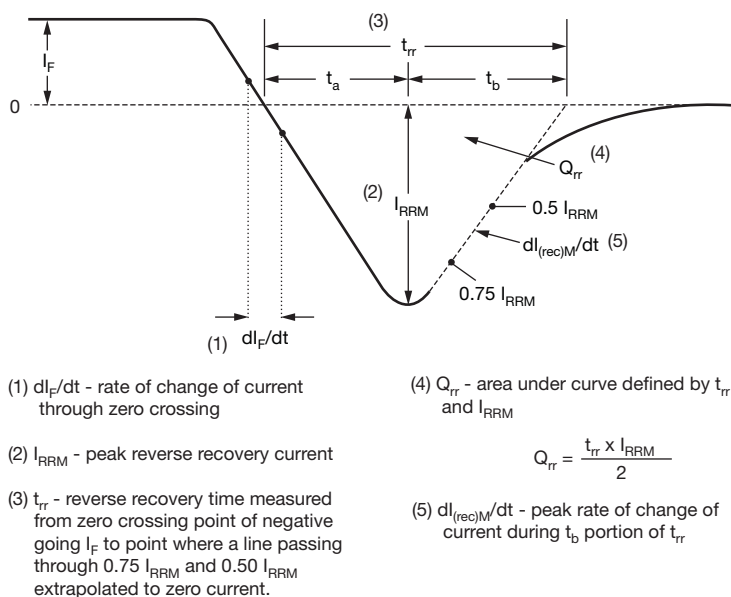


Fig. 10 - Reverse Recovery Waveform and Definitions

VS-6EWX06FN-M3

Vishay Semiconductors Hyperfast Rectifier, 6 A FRED Pt®

**ORDERING INFORMATION TABLE**

Device code	VS-	6	E	W	X	06	FN	TRL	-M3
	1	2	3	4	5	6	7	8	9
1	- Vishay Semiconductors product								
2	- Current rating (6 = 6 A)								
3	- Circuit configuration: E = Single diode								
4	- Package identifier: W = D-PAK								
5	- X = Hyperfast recovery time								
6	- Voltage rating (06 = 600 V)								
7	- FN = TO-252AA								
8	- - None = Tube - TR = Tape and reel - TRL = Tape and reel (left oriented) - TRR = Tape and reel (right oriented)								
9	- Environmental digit: -M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free								

ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-6EWX06FN-M3	75	3000	Antistatic plastic tube
VS-6EWX06FNTR-M3	2000	2000	13" diameter reel
VS-6EWX06FNTRL-M3	3000	3000	13" diameter reel
VS-6EWX06FNTRR-M3	3000	3000	13" diameter reel

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95016
Part marking information	www.vishay.com/doc?95176
Packaging information	www.vishay.com/doc?95033
SPICE model	www.vishay.com/doc?95216



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